

PCRKA20075F8

750 V, 200 A Extremefast Diode Die

Features

- AEC-Q101 Rev. D Qualified for Enhanced Reliability
- Maximum Junction Temperature 175°C
- Extremefast Technology with Soft Recovery
- Low Forward Voltage: $V_F = 1.5 \text{ V(Typ.)}@I_F = 200 \text{ A}$

Applications

- Automotive Traction Modules
- General Power Modules

MECHANICAL PARAMETERS

Parameter	Mils	μm
Die Size	394 x 197	10,000 x 5,000
Anode Pad Size	176 x 373	8,776 x 3,776
Die Thickness	3.62	92
Top Metal	6 μm AlSiCu	
Back Metal	1.4 μm Ti/NiV/Ag	
Topside Passivation	Silicon Nitride plus Polyimide	
Wafer Diameter	200 mm	
Max Possible Die Per Wafer	467	
Recommended Storage Environment	In original container, in dry nitrogen, < 3 months at an ambient temperature of 23°C	

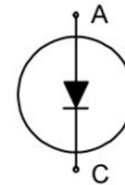


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$V_{RRM} = 750\text{V}$
 $I_F = \text{Limited by } T_{j(\text{max})}$

DIODE DIE



DIE OUTLINE



ORDERING INFORMATION

Device	Inking?	Shipping
PCRKA20075F8	Yes	Sawn Wafer on Tape

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ABSOLUTE MAXIMUM RATINGS ($T_{VJ} = 25^{\circ}\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	Ratings	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	750	V
DC Forward Current, limited by T_{VJ} max	I_F	(Note 1)	A
Pulsed Forward Current, t_p limited by T_{VJ} max (Note 2)	I_{FM}	600	A
Operating Junction Temperature	T_{VJ}	-40 to +175	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-17 to +25	$^{\circ}\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Depends on the thermal properties of assembly.
2. Not subject to production test – verified by design/characterization.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
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STATIC CHARACTERISTICS (Tested on Wafers)

Breakdown Voltage	V_{BR}	$I_R = 1\text{ mA}$	750	–	–	V
Reverse Leakage Current	I_R	$V_R = 750\text{ V}$	–	–	30	μA
Forward Voltage	V_F	$I_F = 100\text{ A}$	1.0	1.25	1.5	V

ELECTRICAL CHARACTERISTICS (Not Subjected to Production Test – Verified by Design/Characterization)

Breakdown Voltage	V_{BR}	$I_R = 1\text{ mA}$	$T_{VJ} = -40^{\circ}\text{C}$	700	800	–	V
Forward Voltage	V_F	$I_F = 200\text{ A}$	$T_{VJ} = 25^{\circ}\text{C}$	–	1.50	1.9	V
			$T_{VJ} = 150^{\circ}\text{C}$	–	1.49	–	V
			$T_{VJ} = 175^{\circ}\text{C}$	–	1.49	–	V
Reverse Recovery Charge	Q_{rr}	$I_F = 200\text{ A } V_R = 400\text{ V},$ $di_F/dt = 500\text{ A}/\mu\text{s}, T_{VJ} = 25^{\circ}\text{C}$	–	2.15	–	μC	
Reverse Recovery Current	I_{rr}		–	24	–	A	
Reverse Recover Time	T_{rr}		–	176	–	nS	
Reverse Recovery Charge	Q_{rr}	$I_F = 200\text{ A } V_R = 400\text{ V},$ $di_F/dt = 500\text{ A}/\mu\text{s}, T_{VJ} = 150^{\circ}\text{C}$	–	8.5	–	μC	
Reverse Recovery Current	I_{rr}		–	50	–	A	
Reverse Recover Time	T_{rr}		–	340	–	nS	
Reverse Recovery Charge	Q_{rr}	$I_F = 200\text{ A } V_R = 400\text{ V},$ $di_F/dt = 500\text{ A}/\mu\text{s}, T_{VJ} = 175^{\circ}\text{C}$	–	10.5	–	μC	
Reverse Recovery Current	I_{rr}		–	54	–	A	
Reverse Recover Time	T_{rr}		–	376	–	nS	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching characteristics and thermal properties are depending strongly on module design and mounting technology.

For ordering, technique and other information on ON Semiconductor automotive bare die products, please contact automotivebaredie@onsemi.com.

Die Layout

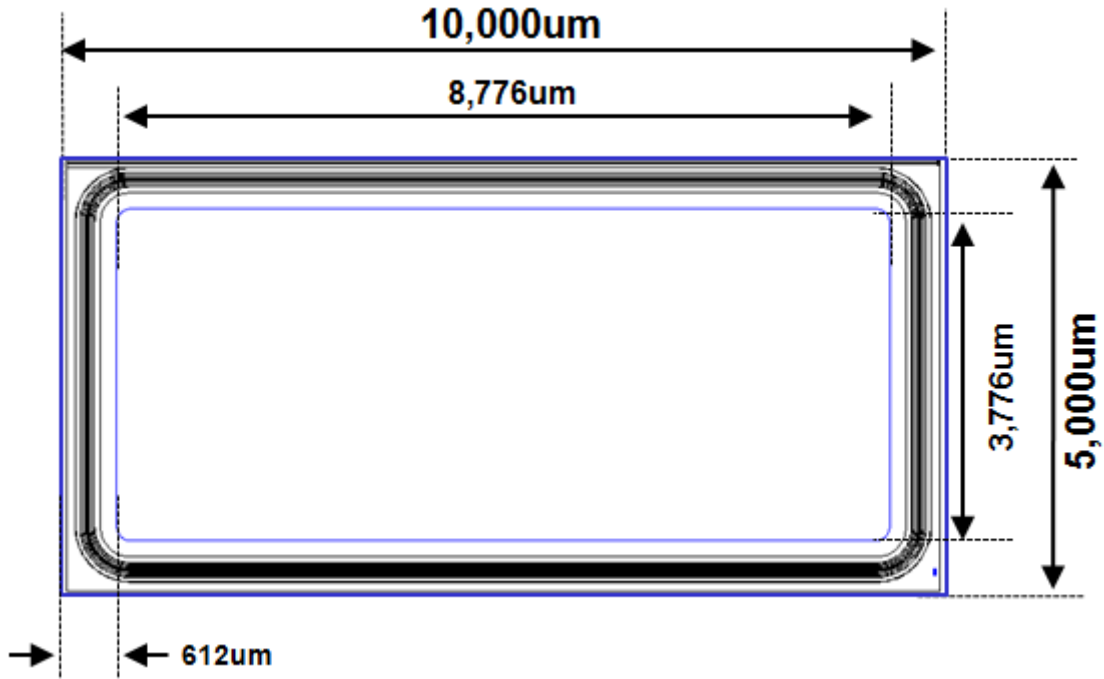


Figure 1. Die Layout

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